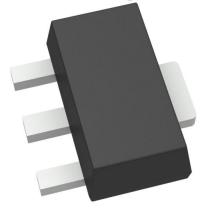


# FCX458TA Datasheet

www.digi-electronics.com

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DiGi Electronics Part Number	FCX458TA-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	FCX458TA
Description	TRANS NPN 400V 0.225A SOT89-3
Detailed Description	Bipolar (BJT) Transistor NPN 400 V 225 mA 50MHz 1 W Surface Mount SOT-89-3

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FCX458TA	Diodes Incorporated
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	225 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
400 V	500mV @ 6mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA	100 @ 50mA, 10V
Power - Max:	Frequency - Transition:
1 W	50MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-243AA	SOT-89-3
Base Product Number:	
FCX458	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	





# FCX458

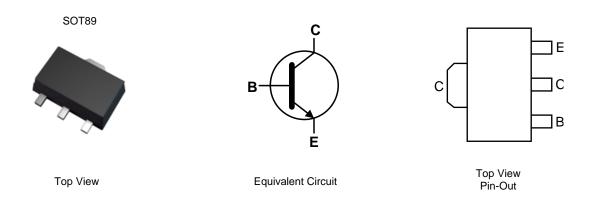
#### 400V NPN HIGH VOLTAGE TRANSISTOR IN SOT89

#### **Features**

- BV<sub>CEO</sub> > 400V
- I<sub>C</sub> = 225mA Continuous Collector Current
- I<sub>CM</sub> = 500mA Peak Pulse Current
- Excellent h<sub>FE</sub> Characteristics up to 100mA
- Low saturation voltage V<sub>CE(sat)</sub> < 200mV @ 20mA</li>
- Complementary PNP Type: FCX558
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.055 grams (Approximate)



# Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX458TA	AEC-Q101	N58	7	12mm	1,000

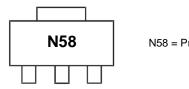
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



N58 = Product Type Marking Code



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	400	V
Collector-Emitter Voltage	V <sub>CEO</sub>	400	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	225	mA
Peak Pulse Current	I <sub>CM</sub>	500	mA
Base Current	IB	200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	(Note 5)		0.7	
Power Dissignation	(Note 6)		1	W
Power Dissipation	(Note 7)	PD	1.5	vv
	(Note 8)	1	2	
	(Note 5)		178	°C/W
ermal Resistance, Junction to Ambient Air	(Note 6)		125	
Thermal Resistance, Junction to Ambient All	(Note 7)	R <sub>θJA</sub>	83	
	(Note 8)		60	
Thermal Resistance, Junction to Lead	(Note 9)	$R_{ ext{ heta}JL}$	22	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

#### ESD Ratings (Note 10)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the exposed collector pad on minimum recommended pad layout (MRP) 1oz copper that is on a single-sided

1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

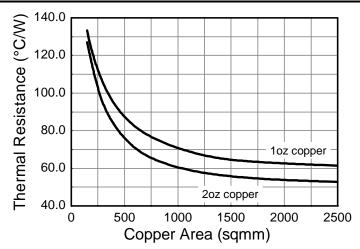
6. Same as Note 5, except the device is mounted with the exposed collector pad on 15mm x 15mm 1oz copper.

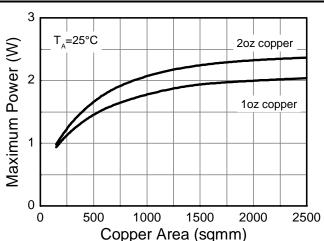
7. Same as Note 5, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.

8. Same as Note 5, except the device is mounted with the exposed collector pad on 50mm x 50mm 1oz copper.

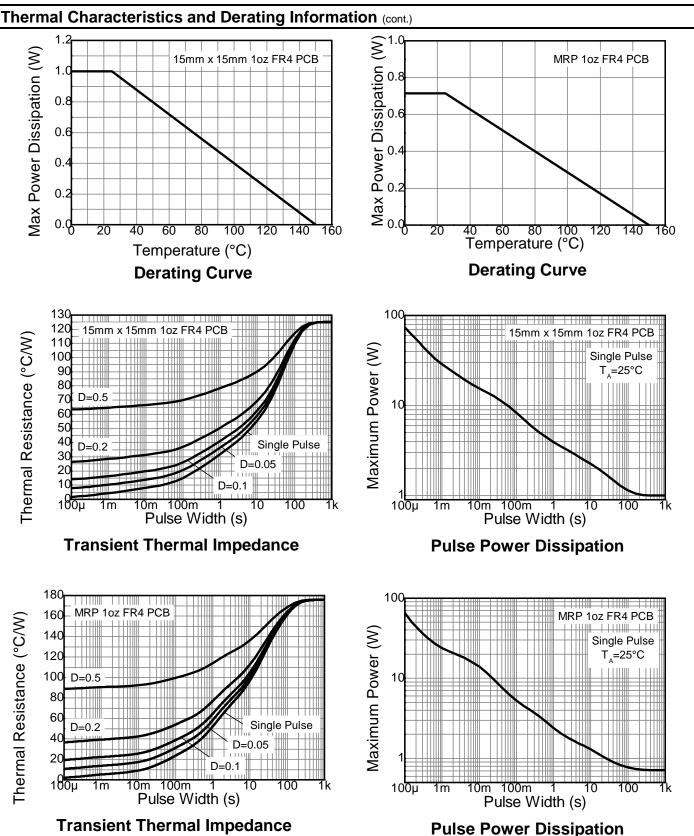
Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Thermal Characteristics and Derating Information











# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

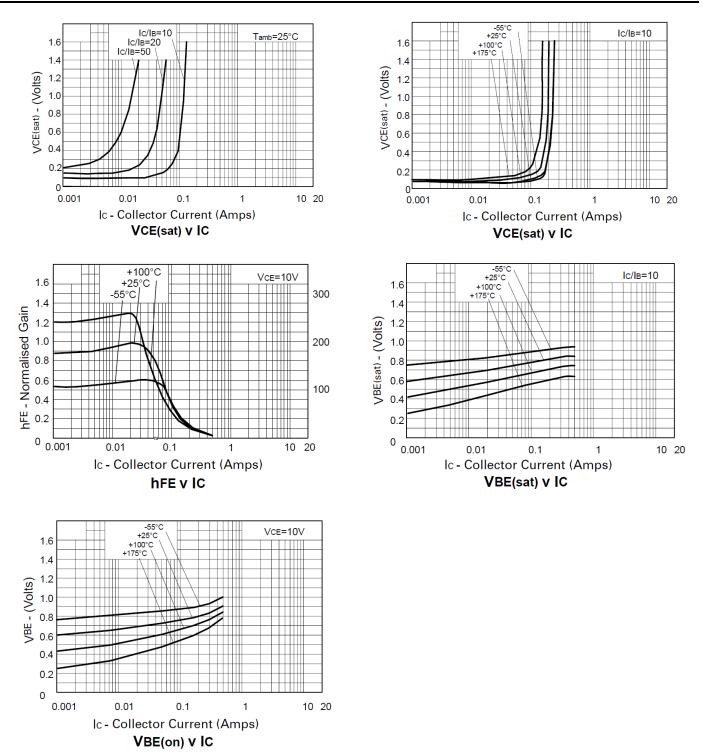
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	400	550	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	400	550		V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	400	450	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	_	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	Ісво	_	<1	100	nA	V <sub>CB</sub> = 320V
Collector Cutoff Current	I <sub>CES</sub>	_	<1	100	nA	V <sub>CES</sub> = 320V
Emitter Cutoff Current	I <sub>EBO</sub>	—	<1	20	nA	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	_	_	200 500	mV	$I_C = 20mA$ , $I_B = 2mA$ $I_C = 50mA$ , $I_B = 6mA$
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	—	_	900	mV	$I_{C} = 50 \text{mA}, I_{B} = 5 \text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	—	_	900	mV	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$
DC Current Gain (Note 11)	hFE	100 100 15	_	300	_	$I_{C} = 1mA, V_{CE} = 10V$ $I_{C} = 50mA, V_{CE} = 10V$ $I_{C} = 100mA, V_{CE} = 10V$
Transitional Frequency	f <sub>T</sub>	50	—	—	MHz	$I_C = 10mA$ , $V_{CE} = 20V$ , f = 20MHz
Output Capacitance	C <sub>obo</sub>	_	_	5	pF	V <sub>CB</sub> = 20V. f = 1MHz
Turn-On Time	t <sub>on</sub>	—	135	_	ns	I <sub>C</sub> =50mA, V <sub>CE</sub> =100V,
Turn-Off Time	t <sub>off</sub>	_	2260	_	ns	I <sub>B1</sub> = 5mA, I <sub>B2</sub> = -10mA

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%



FCX458

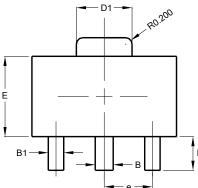
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

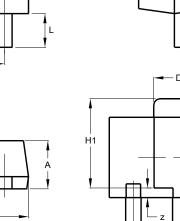




# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





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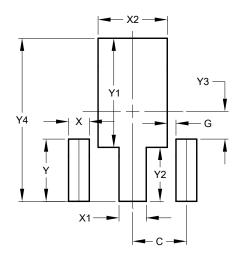
SOT89						
Dim	Min Max Typ					
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
E	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	Dimens	sions in	mm			

# Suggested Pad Layout

D

·8°( \*4)

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value	
Dimensions	(in mm)	
С	1.500	
G	0.244	
Х	0.580	
X1	0.760	
X2	1.933	
Ŷ	1.730	
Y1	3.030	
Y2	1.500	
Y3	0.770	
Y4	4.530	

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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